

# **Excellent Integrated System Limited**

Stocking Distributor

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<u>Vishay Semiconductor/Diodes Division</u> <u>VS-MBRS140-M3/5BT</u>

For any questions, you can email us directly: <a href="mailto:sales@integrated-circuit.com">sales@integrated-circuit.com</a>

### Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite Datasheet of VS-MBRS140-M3/5BT - DIODE SCHOTTKY 40V 1A DO214AA

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www.vishay.com

### **VS-MBRS140-M3**

RoHS

COMPLIANT

Vishay Semiconductors

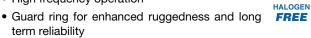
## High Performance Schottky Rectifier, 1.0 A



PRODUCT SUMMARY				
Package	SMB			
I <sub>F(AV)</sub>	1.0 A			
V <sub>R</sub>	40 V			
V <sub>F</sub> at I <sub>F</sub>	0.53 V			
I <sub>RM</sub> max.	4.0 mA at 125 °C			
T <sub>J</sub> max.	125 °C			
Diode variation	Single die			
E <sub>AS</sub>	3.0 mJ			

### **FEATURES**

- Small foot print, surface mountable
- · Low forward voltage drop
- High frequency operation





• Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### **DESCRIPTION**

The VS-MBRS140-M3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS				
SYMBOL	CHARACTERISTICS	VALUES	UNITS	
I <sub>F(AV)</sub>	Rectangular waveform	1.0	Α	
V <sub>RRM</sub>		40	V	
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	380	Α	
V <sub>F</sub>	1.0 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.53	V	
T <sub>J</sub>	Range	-55 to +150	°C	

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-MBRS140-M3	UNITS	
Maximum DC reverse voltage	$V_{R}$	40	V	
Maximum working peak reverse voltage	V <sub>RWM</sub>	40	V	

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current	I <sub>F(AV)</sub>	50 % duty cycle at T <sub>L</sub> = 119 °C, rectangular waveform		1.0	
Maximum peak one cycle non-repetitive surge current	_	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V <sub>RRM</sub> applied	380	А
	IFSM	10 ms sine or 6 ms rect. pulse		40	
Non-repetitive avalanche energy	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1 A, L = 6 mH		3.0	mJ
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s  Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical		Α	

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### **VS-MBRS140-M3**

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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNITS
	V <sub>FM</sub> <sup>(1)</sup>	1 A	T <sub>J</sub> = 25 °C	0.52	0.6	V
Maximum forward voltage drap		2 A		0.70	0.77	
Maximum forward voltage drop		1 A	T <sub>J</sub> = 125 °C	0.48	0.53	
		2 A		0.63	0.71	
Maximum reverse leakage current I <sub>RM</sub>	ı (1)	T <sub>J</sub> = 25 °C	$V_R = Rated V_R$	-	0.1	mA
	IRM (')	T <sub>J</sub> = 125 °C		-	4.0	IIIA
Maximum junction capacitance	C <sub>T</sub>	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		-	80	pF
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body		-	2.0	nH
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		-	10 000	V/µs

#### Note

 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T <sub>J</sub> <sup>(1)</sup> , T <sub>Stg</sub>		-55 to +150	°C
Maximum thermal resistance, junction to lead	R <sub>thJL</sub> <sup>(2)</sup>	DC operation See fig. 4	36	°C/W
Maximum thermal resistance, junction to ambient	R <sub>thJA</sub>	DC operation	80	C/VV
Approximate weight			0.10	g
Approximate weight			0.003	OZ.
Marking device		Case style SMB (similar to DO-214AA)	1	4

### Notes

 $<sup>\</sup>frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$  thermal runaway condition for a diode on its own heatsink

<sup>(2)</sup> Mounted 1" square PCB

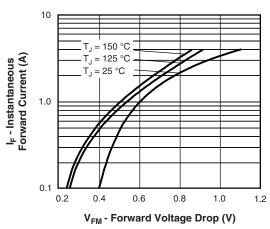


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Fig. 1 - Maximum Forward Voltage Drop Characteristics

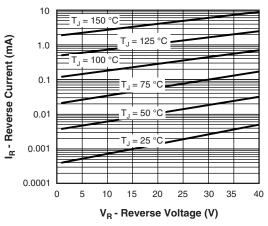


Fig. 2 - Typical Peak Reverse Current vs. Reverse Voltage

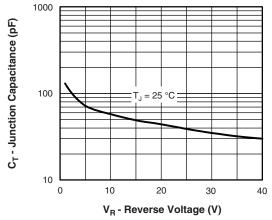


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

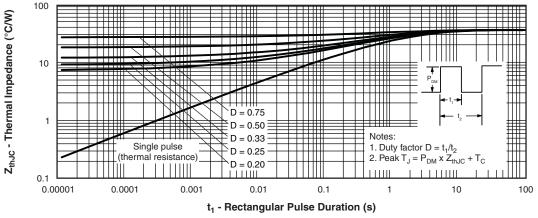


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics (Per Leg)

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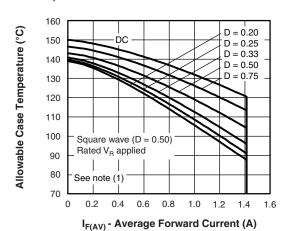


Fig. 5 - Maximum Average Forward Current vs. Allowable Lead Temperature

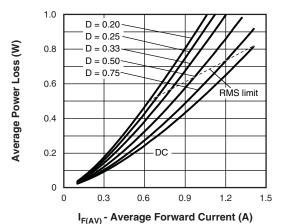


Fig. 6 - Maximum Average Forward Dissipation vs.
Average Forward Current

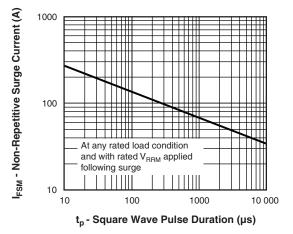


Fig. 7 - Maximum Peak Surge Forward Current vs. Pulse Duration

### Note

 $^{(1)}$  Formula used: T<sub>C</sub> = T<sub>J</sub> - (Pd + Pd<sub>REV</sub>) x R<sub>th,JC</sub>; Pd = Forward power loss = I<sub>F(AV)</sub> x V<sub>FM</sub> at (I<sub>F(AV)</sub>/D) (see fig. 6); Pd<sub>REV</sub> = Inverse power loss = V<sub>R1</sub> x I<sub>R</sub> (1 - D); I<sub>R</sub> at V<sub>R1</sub> = 80 % rated V<sub>R</sub>

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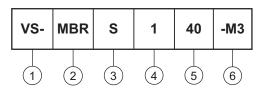


### **VS-MBRS140-M3**

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### **ORDERING INFORMATION TABLE**

Device code



- 1 Vishay Semiconductors products
- 2 Schottky MBR series
- 3 S = SMB
- 4 Current rating (1 = 1 A)
- 5 Voltage rating (40 = 40 V)
- 6 -M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N	PREFERRED PACKAGE CODE   MINIMUM ORDER QUANTITY   PACKAGING DESCRIPTION				
VS-MBRS140-M3/5BT	5BT	3200	13" diameter plastic tape and reel		

LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?95401</u>				
Part marking information	www.vishay.com/doc?95403			
Packaging information	www.vishay.com/doc?95404			
SPICE model	www.vishay.com/doc?95299			

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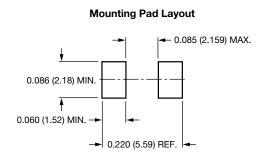
### **Outline Dimensions**

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## **SMB**

### **DIMENSIONS** in inches (millimeters)

# 0.086 (2.20) 0.077 (1.95) 0.180 (4.57) 0.160 (4.06) 0.096 (2.44) 0.084 (2.13) 0.060 (1.52) 0.008 (0.2) 0.0220 (5.59) 0.205 (5.21)





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